

1. Global joint venture starts operations as WeEn Semiconductors

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As from November 9th, 2015 NXP Semiconductors N.V. and Beijing JianGuang Asset Management Co. Ltd established Bipolar Power joint venture (JV), **WeEn Semiconductors**, which will be used in future Bipolar Power documents together with new contact details.

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Thank you for your cooperation and understanding,

WeEn Semiconductors





Product data sheet

1. General description

Planar passivated high commutation three quadrant triac in a SOT54 (TO-92) plastic package. This "series B" triac is designed to commutate the full RMS current at the maximum junction temperature without the aid of a snubber.

2. Features and benefits

- 3Q technology for improved noise immunity
- High commutation capability with maximum false trigger immunity
- High voltage capability
- Less sensitive gate for highest noise immunity
- · Planar passivated for voltage ruggedness and reliability
- Triggering in three quadrants only
- Very high immunity to false turn-on by dV/dt

3. Applications

- General purpose motor control
- Small loads in washing machines
- Solenoid drivers

4. Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|---------------------|---------------------------------------|---|-----|-----|-----|------|
| V _{DRM} | repetitive peak off- state voltage | | - | - | 600 | V |
| I _{T(RMS)} | RMS on-state current | full sine wave; $T_{lead} \le 54 \text{ °C}$; Fig. 1; Fig. 2; Fig. 3 | - | - | 1 | A |
| Static characte | eristics | | | | | |
| I _{GT} | gate trigger current | V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u> | 5 | - | 50 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u> | 5 | - | 50 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u> | 5 | - | 50 | mA |

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5. Pinning information

| Table 2. Pinning information | | | | | | | |
|------------------------------|--------|-----------------|---|----------------|--|--|--|
| Pin | Symbol | Description | Simplified outline | Graphic symbol | | | |
| 1 | T2 | main terminal 2 | | T2T1 | | | |
| 2 | G | gate | | Sym051 | | | |
| 3 | T1 | main terminal 1 | () () () () () () () () () () () () () (| Symost | | | |

6. Ordering information

| Table 3. Ordering information | | | | | | |
|-------------------------------|---------|---|---------|--|--|--|
| Type number | Package | | | | | |
| | Name | Description | Version | | | |
| BTA201-600B | TO-92 | plastic single-ended leaded (through hole) package; 3 leads | SOT54 | | | |

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|---------------------|-----------------------------------|---|-----|------|------|
| V _{DRM} | repetitive peak off-state voltage | | - | 600 | V |
| I _{T(RMS)} | RMS on-state current | full sine wave; $T_{lead} \le 54$ °C; <u>Fig. 1; Fig. 2</u> ; Fig. 3 | - | 1 | A |
| I _{TSM} | non-repetitive peak on- | full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.8 ms | - | 13.7 | А |
| | state current | full sine wave; $T_{j(init)}$ = 25 °C; t_p = 20 ms; Fig. 4; Fig. 5 | - | 12.5 | A |
| l ² t | I ² t for fusing | t _p = 10 ms; SIN | - | 0.78 | A²s |
| dl _T /dt | rate of rise of on-state current | I _G = 0.2 A | - | 100 | A/µs |
| I _{GM} | peak gate current | | - | 2 | А |
| P _{GM} | peak gate power | | - | 5 | W |
| P _{G(AV)} | average gate power | over any 20 ms period | - | 0.1 | W |
| Tj | junction temperature | | -40 | 125 | °C |

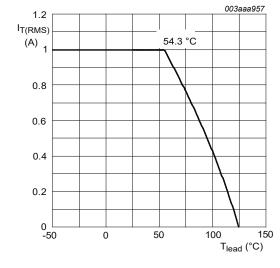
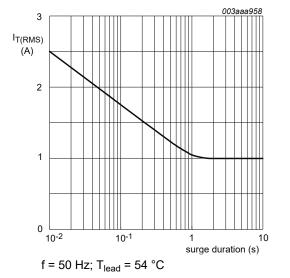
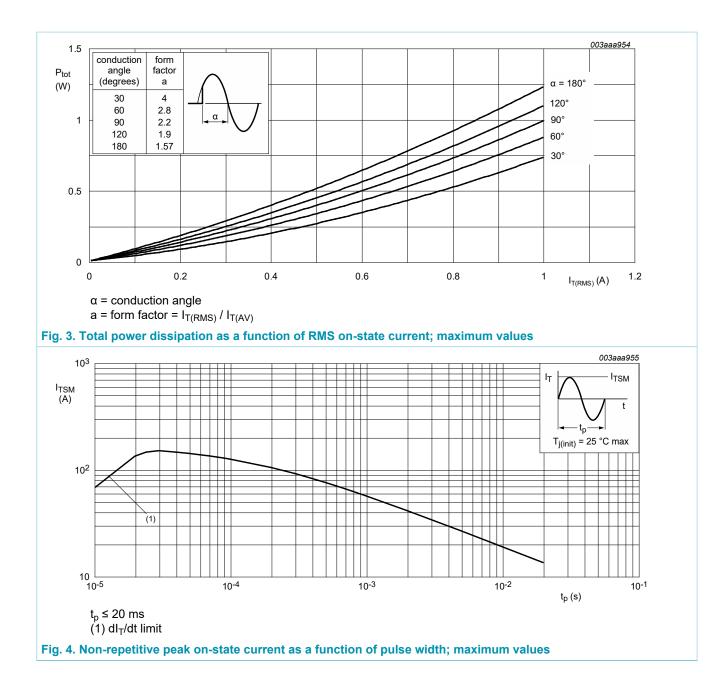


Fig. 1. RMS on-state current as a function of lead temperature; maximum values





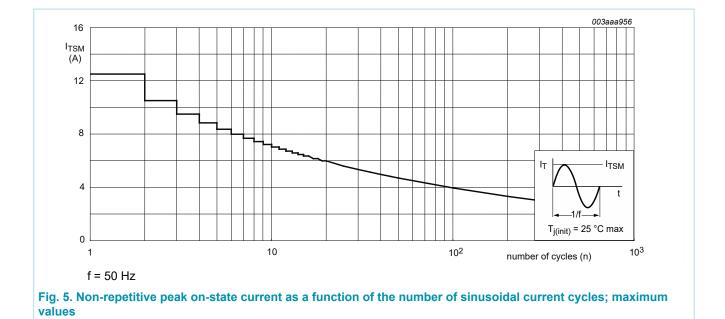
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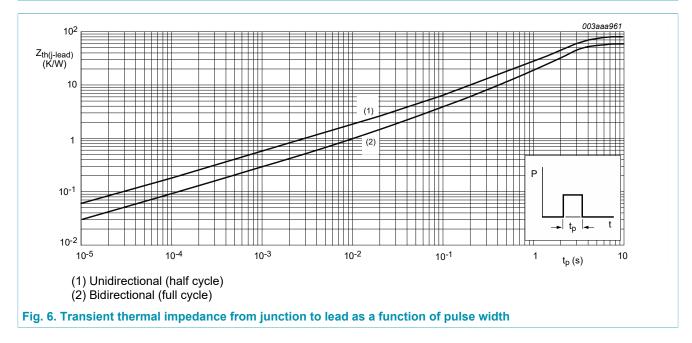




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8. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-------------------------|--|--|-----|-----|-----|------|
| R _{th(j-lead)} | thermal resistance | full cycle; <u>Fig. 6</u> | - | - | 60 | K/W |
| | from junction to lead | half cycle; <u>Fig. 6</u> | - | - | 80 | K/W |
| R _{th(j-a)} | thermal resistance from junction to ambient free air | printed circuit board mounted; lead length = 4 mm | - | 150 | - | K/W |



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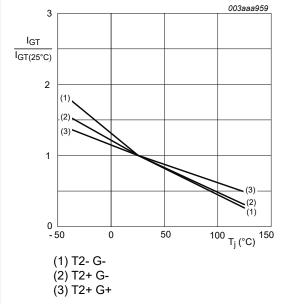
9. Characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|---------------------------------------|---|------|-----|-----|------|
| Static chara | acteristics | | | | | |
| I _{GT} | gate trigger current | V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u> | 5 | - | 50 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u> | 5 | - | 50 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u> | 5 | - | 50 | mA |
| ΙL | latching current | V_D = 12 V; I _G = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 8</u> | - | - | 30 | mA |
| | | V_D = 12 V; I _G = 0.1 A; T2+ G-; T _j = 25 °C; Fig. 8 | - | - | 50 | mA |
| | | V_D = 12 V; I _G = 0.1 A; T2- G-; T _j = 25 °C; Fig. 8 | - | - | 30 | mA |
| I _H | holding current | V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u> | - | - | 30 | mA |
| V _T | on-state voltage | I _T = 1.4 A; T _j = 25 °C; <u>Fig. 10</u> | - | 1.2 | 1.5 | V |
| V _{GT} | gate trigger voltage | V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; Fig. 11 | - | 0.7 | 1 | V |
| | | V _D = 400 V; I _T = 0.1 A; T _j = 125 °C; Fig. 11 | 0.2 | 0.3 | - | V |
| I _D | off-state current | V _D = 600 V; T _j = 125 °C | - | 0.1 | 0.5 | mA |
| Dynamic ch | naracteristics | | | | | |
| dV _D /dt | rate of rise of off-state voltage | V_{DM} = 402 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit; Fig. 12 | 1000 | - | - | V/µs |
| dl _{com} /dt | rate of change of commutating current | V_D = 400 V; T _j = 125 °C; I _{T(RMS)} = 1 A; dV _{com} /dt = 20 V/s; (snubberless condition); gate open circuit | 12 | - | - | A/m |
| | | V_D = 400 V; T _j = 125 °C; I _{T(RMS)} = 1 A; dV _{com} /dt = 10 V/µs; gate open circuit | 16 | - | - | A/m |

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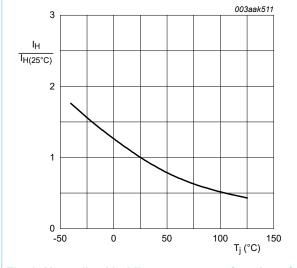
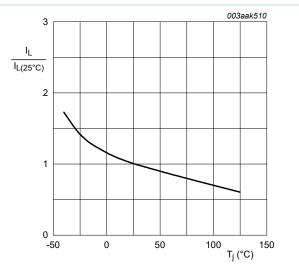
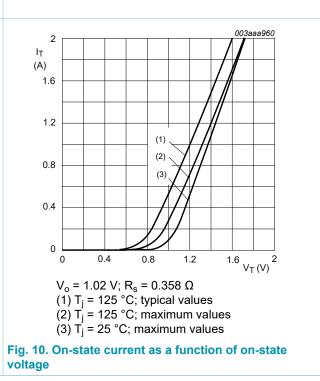


Fig. 9. Normalized holding current as a function of junction temperature



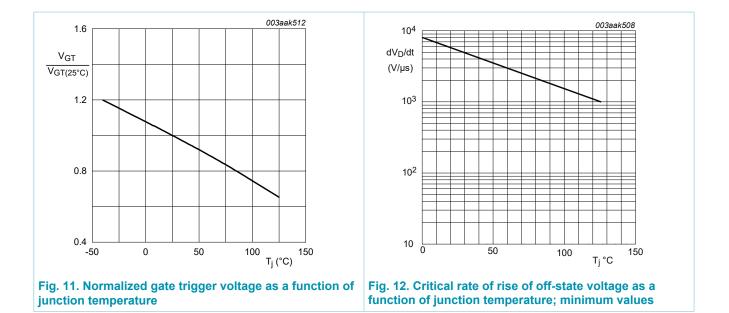




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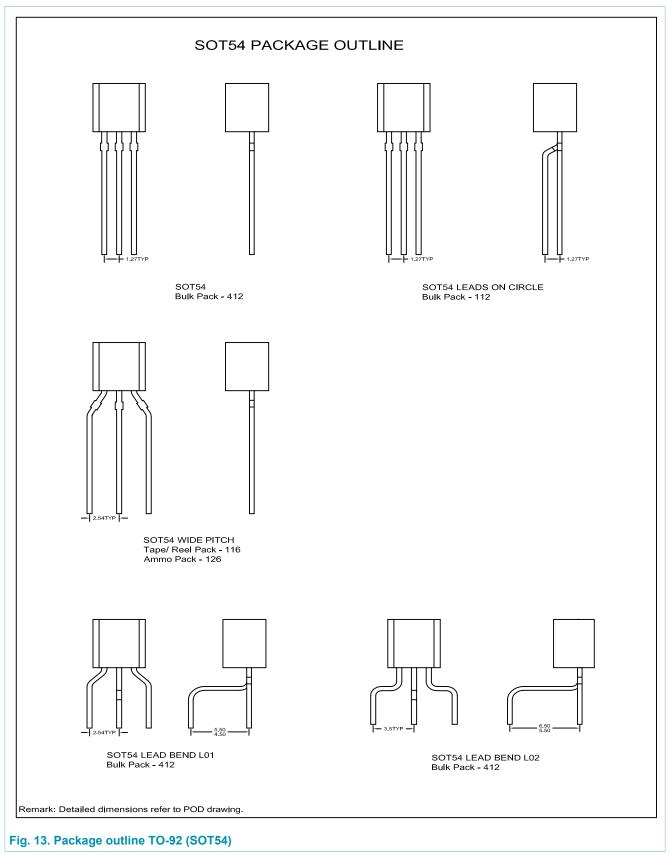
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10. Package outline



Product data sheet

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|--------------------------------------|-------------------------------|---|
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